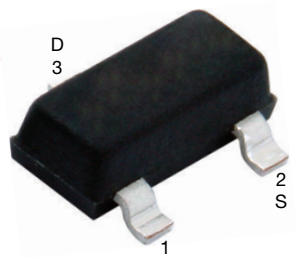
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Automotive P-Channel 20 V (D-S) 175 °C MOSFET

SOT-23 (TO-236)



Top View

Marking Code: 9Qxxx

FEATURES

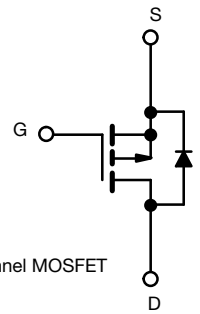
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

Pb-free

RoHS COMPLIANT

HALOGEN FREE



P-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	-20
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.115
$R_{DS(on)}$ (Ω) at V_{GS} = -2.5 V	0.205
I_D (A)	-3.2
Configuration	Single

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2351CES (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-20	V
Gate-source voltage		V_{GS}	± 12	
Continuous drain current	T_C = 25 °C	I_D	-3.2	A
	T_C = 125 °C		-1.8	
Continuous source current (diode conduction)		I_S	-2.5	
Pulsed drain current [a]		I_{DM}	-12.7	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	-6	
Single pulse avalanche energy		E_{AS}	1.8	mJ
Maximum power dissipation	T_C = 25 °C	P_D	2	W
	T_C = 125 °C		0.67	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount [b]	R_{thJA}	175	°C/W
Junction-to-foot (drain)		R_{thJF}	75	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. When mounted on 1" square PCB (FR4 material)

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0, I_D = -250 µA		-20	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA		-0.6	-1.0	-1.5	
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 12 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{GS} = 0 V	V_{DS} = -20 V	-	-	-1	µA
		V_{GS} = 0 V	V_{DS} = -20 V, T_J = 125 °C	-	-	-50	
		V_{GS} = 0 V	V_{DS} = -20 V, T_J = 175 °C	-	-	-150	
On-state drain current [a]	$I_{D(on)}$	V_{GS} = -4.5 V	V_{DS} ≥ 5 V	-8	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = -4.5 V	I_D = -2.4 A	-	0.080	0.115	Ω
		V_{GS} = -4.5 V	I_D = -2.4 A, T_J = 125 °C	-	-	0.168	
		V_{GS} = -4.5 V	I_D = -2.4 A, T_J = 175 °C	-	-	0.196	
		V_{GS} = -2.5 V	I_D = -1.8 A	-	0.150	0.205	
Forward transconductance [b]	g_{fs}	V_{DS} = -10 V, I_D = -2.4 A		-	6	-	S
Dynamic [b]							
Input capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = -10 V, f = 1 MHz	-	265	330	pF
Output capacitance	C_{oss}			-	75	94	
Reverse transfer capacitance	C_{rss}			-	50	63	
Total gate charge [c]	Q_g	V_{GS} = -4.5 V	V_{DS} = -10 V, I_D = -2.4 A	-	3.4	5.5	nC
Gate-source charge [c]	Q_{gs}			-	0.6	-	
Gate-drain charge [c]	Q_{gd}			-	1.1	-	
Gate resistance	R_g	f = 1 MHz		3.0	6.0	14.4	Ω
Turn-on delay time [c]	$t_{d(on)}$	V_{DD} = -10 V, R_L = 5.21 Ω I_D ≅ -1.9 A, V_{GEN} = -4.5 V, R_g = 1 Ω		-	20	30	ns
Rise time [c]	t_r			-	18	27	
Turn-off delay time [c]	$t_{d(off)}$			-	19	28	
Fall time [c]	t_f			-	8	12	
Source-Drain Diode Ratings and Characteristics							
Pulsed current [a]	I_{SM}			-	-	-12.7	A
Forward voltage	V_{SD}	I_F = -2 A, V_{GS} = 0		-	-0.8	-1.2	V
Body diode reverse recovery time	t_{rr}	I_F = -2 A, di/dt = 100 A/µs		-	13	26	ns
Body diode reverse recovery charge	Q_{rr}			-	5	10	nC
Reverse recovery fall time	t_a			-	6	-	ns
Reverse recovery rise time	t_b			-	7	-	
Body diode peak reverse recovery current	$I_{RM(REC)}$			-	-0.89	-	A

Notes

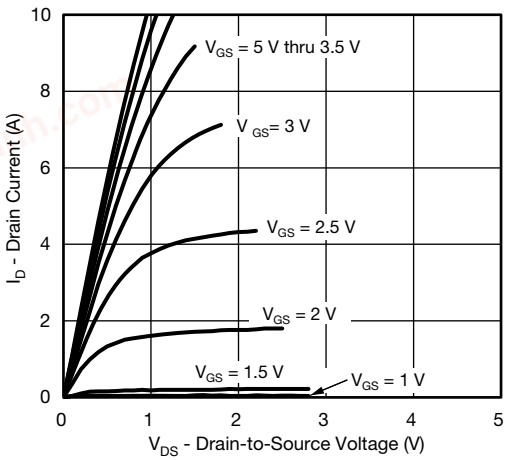
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

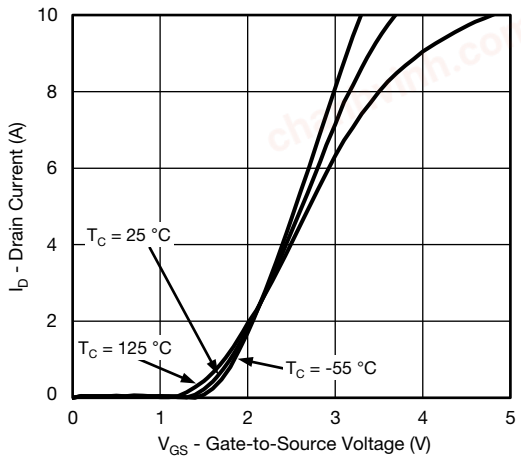
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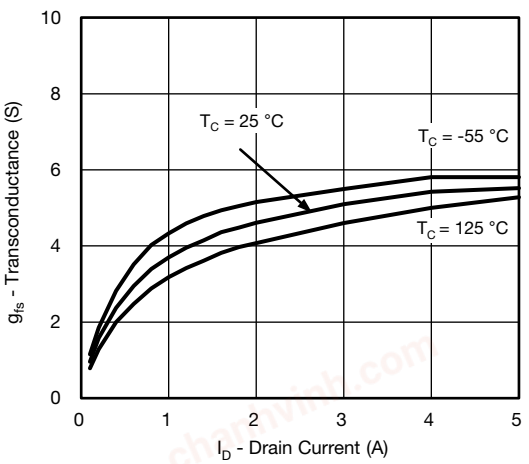
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



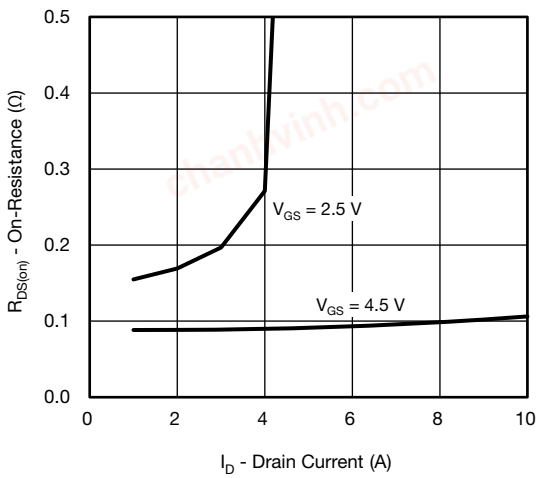
Output Characteristics



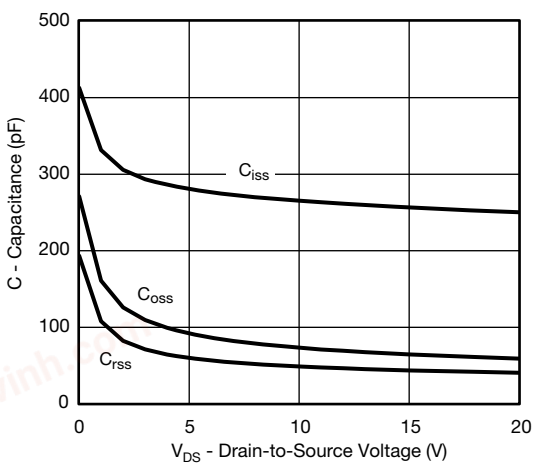
Transfer Characteristics



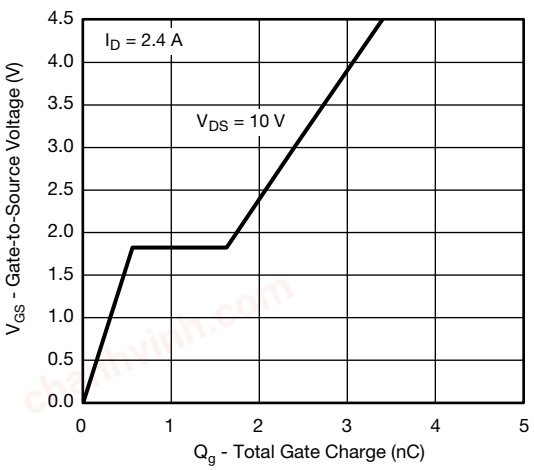
Transconductance



On-Resistance vs. Drain Current



Capacitance

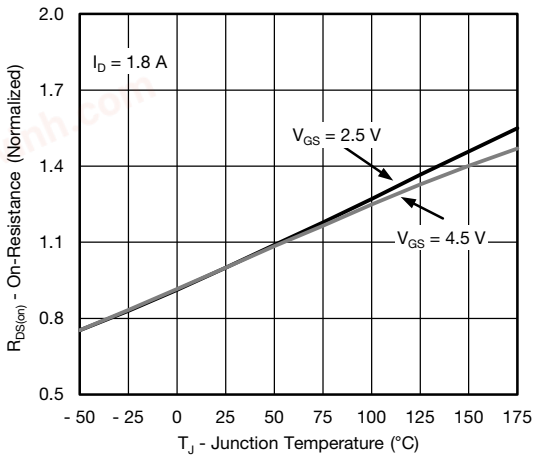


Gate Charge

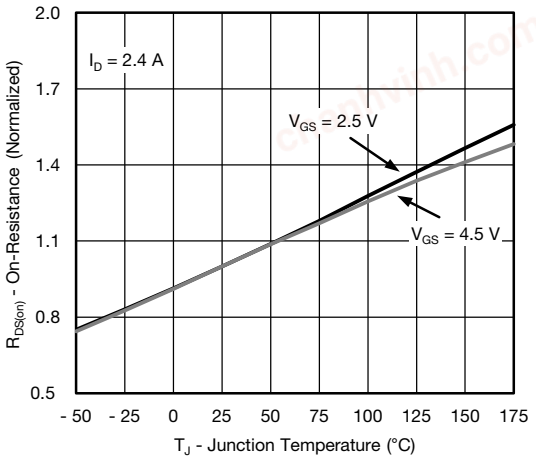
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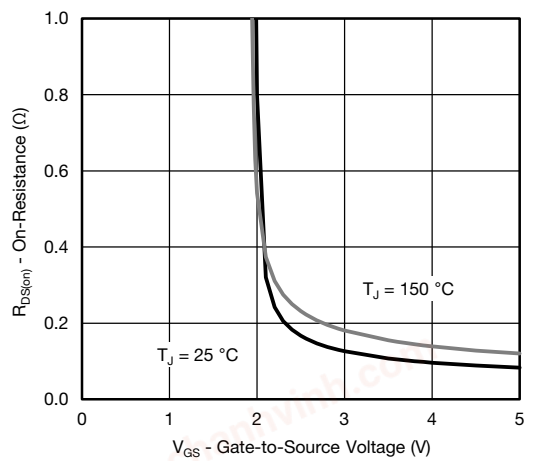
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



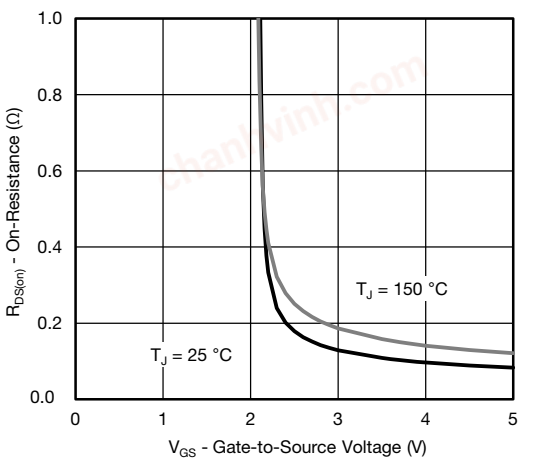
On-Resistance vs. Junction Temperature (1.8 A)



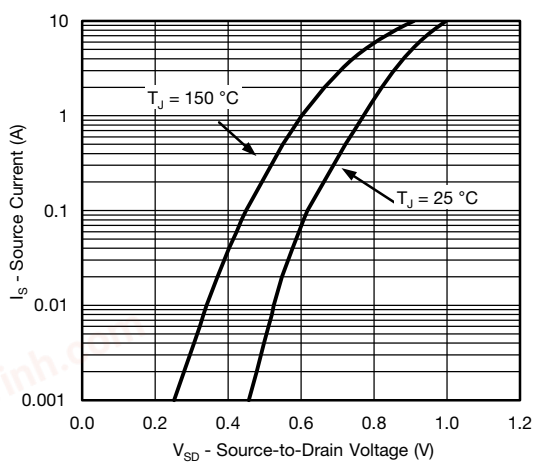
On-Resistance vs. Junction Temperature (2.4 A)



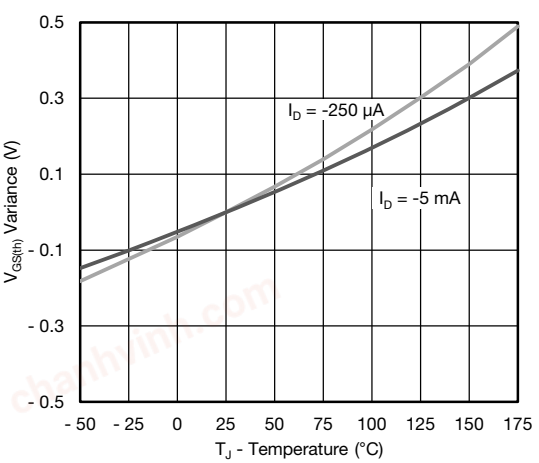
On-Resistance vs. Gate-to-Source Voltage (1.8 A)



On-Resistance vs. Gate-to-Source Voltage (2.4 A)



Source-Drain Diode Forward Voltage

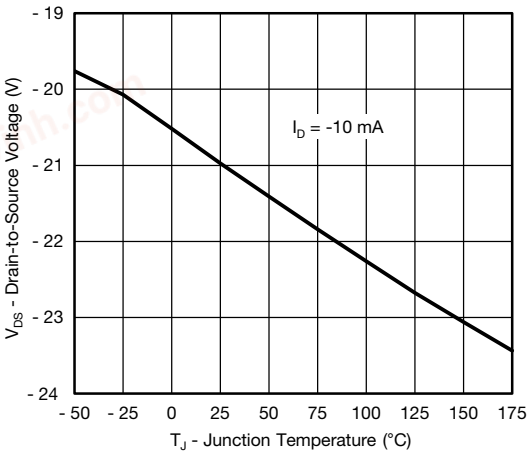


Threshold Voltage

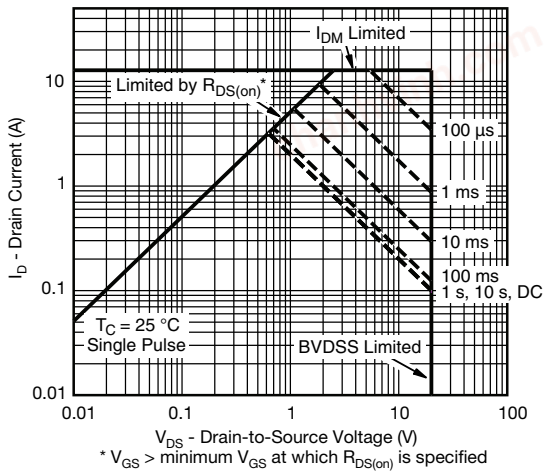
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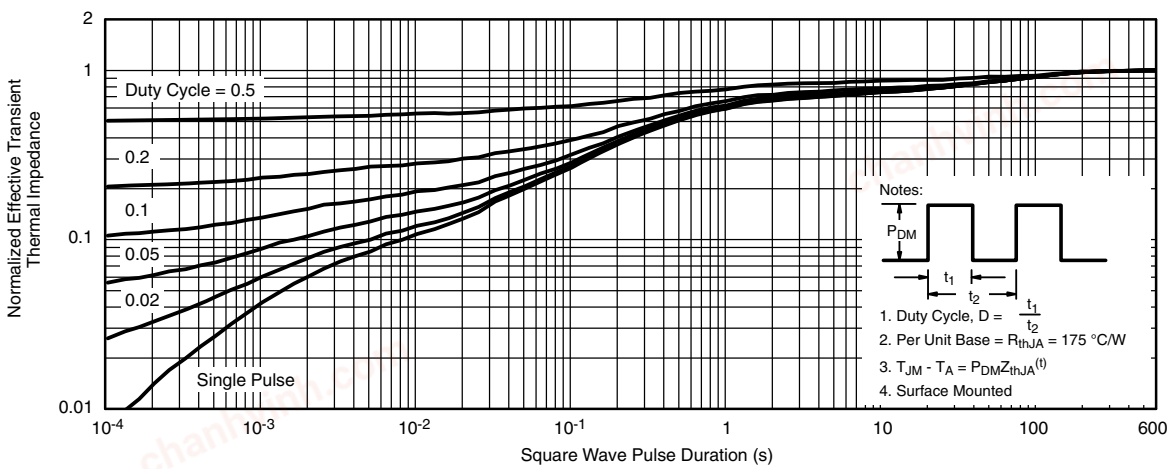
THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area

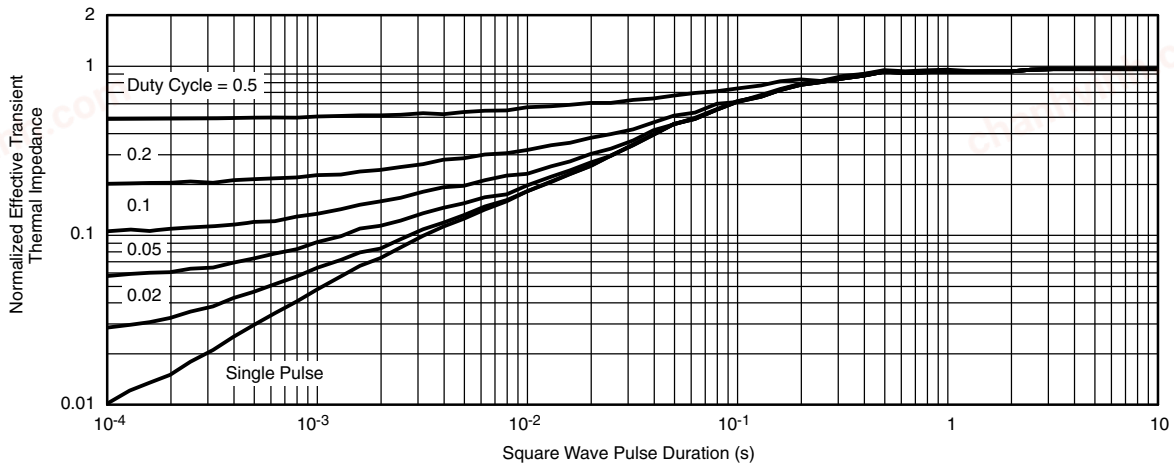


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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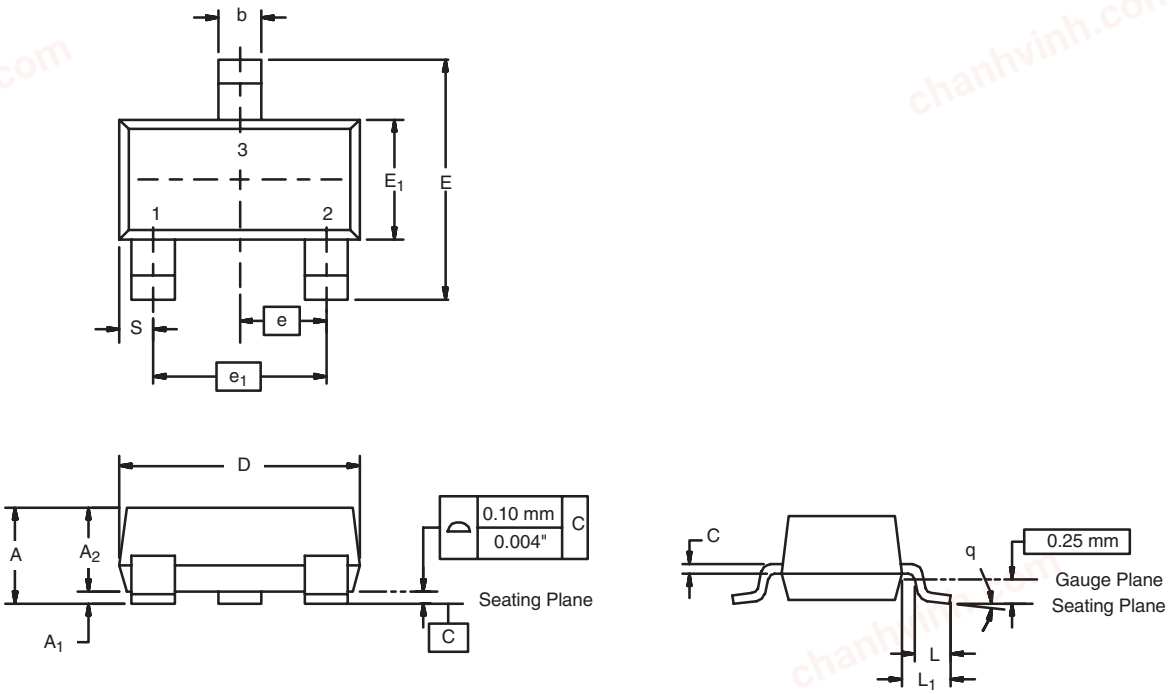
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Package Information

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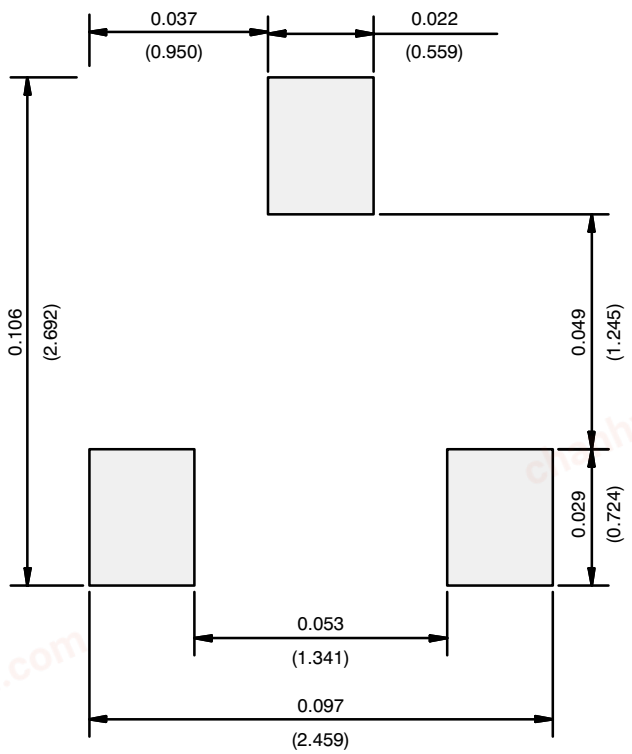
SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A_1	0.01	0.10	0.0004	0.004
A_2	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E_1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e_1	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L_1	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°
ECN: S-03946-Rev. K, 09-Jul-01 DWG: 5479				

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE

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